



12/13/01
1-23-02

PATENT
Customer No. 22,852
Attorney Docket No. 04329.2210

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of:)
)
Katsuhiko HIEDA, et al.) Group Art Unit: 2811
)
Serial No.: 09/469,190) Examiner: Hung K. Vu
)
Filed: December 21, 1999)
)
For: SEMICONDUCTOR DEVICE AND)
METHOD FOR)
MANUFACTURING THE SAME)

Assistant Commissioner for Patents
Washington, DC 20231

Sir:

AMENDMENT

In reply to the Office Action dated September 13, 2001, the period for response extending through January 14, 2002 (January 13, 2002 being a Sunday) by the attached Petition for Extension of Time of one (1) month and requisite fee payment, please amend the application as follows:

IN THE CLAIMS:

Please amend claims 10 and 19 as follows:

10. (Amended) A semiconductor device comprising:
- a semiconductor substrate;
 - a conductive plug formed on the semiconductor substrate;
 - a lower electrode formed in contact with the conductive plug and constituted by a plurality of crystal grains, the crystal grains containing a metallic element;
 - a capacitor insulating film formed on a side of the capacitor lower electrode; and

LAW OFFICES

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